

## TECHNOLOGY CENTER R3700

PATENT MIC04 P-113

## THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant

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Group

2835

Confirmation No.

4900

For

ULTRA RAPID THERMAL PROCESSING

CHAMBER AND METHOD OF USE

Commissioner for Patents Washington, D.C. 20231

Dear Sir:

## PRELIMINARY AMENDMENT

Prior to examination, Applicant wishes to amend his application as follows:

## IN THE CLAIMS:

Please add the following new claims:

- The semiconductor processing apparatus according to Claim 4, wherein said 51. (New) second energy source comprises at least one lamp having a normal operating condition generating a normal output spectrum and a normal peak operating voltage, said lamp adapted to apply a high energy voltage to the device side, said high energy voltage exceeding said normal peak operating voltage, and when applying said high energy voltage said lamp generating a shifted output energy spectrum whereby said lamp generates a peak energy voltage at a shorter wavelength than said normal peak operating voltage.
- The semiconductor processing apparatus according to Claim 51, wherein said 52. (New) shifted output energy spectrum generates an output energy over a range of about 0.2 microns to 0.9 microns.
- The semiconductor processing apparatus according to Claim 51, wherein said 53. (New) lamp comprises a tungsten halogen lamp.

